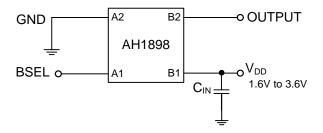


Typical Applications Circuit



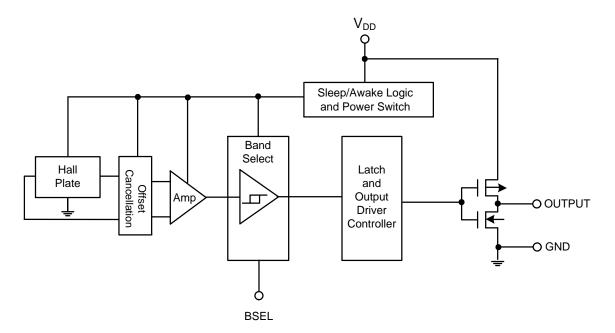
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 100nF typical.

Pin Descriptions

Package: U-WLB0808-4

Pin Number	Pin Name	Function
A1	BSEL	Band Select Pin to Select Operating and Release Gauss Points
A2	GND	Ground Pin
B1	V _{DD}	Power Supply Input
B2	OUTPUT	Output Pin

Functional Block Diagram





Absolute Maximum Ratings (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
V_{DD}	Supply Voltage (Note 6)		6	V
VDD_REV	Reverse Supply Voltage		-0.3	V
Іоитрит	Output Current (Source and Sink)	2.5	mA	
В	Magnetic Flux Density		Unlimited	
PD	Package Power Dissipation U-WLB0808-4		160	mW
Ts	Storage Temperature Range	-65 to +150	°C	
TJ	Maximum Junction Temperature		150	°C
ESD HBM	Human Body Model (HBM) ESD Capability	V _{DD} , GND and OUT Pins	8	kV
LOD HIBINI	Truman body woder (Fibivi) E3D Capability	BSEL Pin	6	kV

Notes:

- 5. Stresses greater than the 'Absolute Maximum Ratings' specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.
- 6. The absolute maximum V_{DD} of 6V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

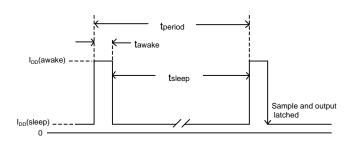
Symbol	Parameter	Conditions	Rating	Unit
V_{DD}	Supply Voltage	Operating	1.6 to 3.6	V
TA	Operating Temperature Range	Operating	-40 to +85	°C

Electrical Characteristics (@TA = +25°C, VDD = 1.8V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vol	Output Low Voltage (ON)	IOUT = 1mA	_	0.1	0.2	V
Vон	Output High Voltage (OFF)	I _{OUT} = -1mA	V _{DD} -0.2	V _{DD} -0.1	_	V
Vsel_lb	Band Select Voltage for Low Band	_	0	_	0.5	V
Vsel_hb	Band Select Voltage for High Band	_	1.4	_	3.6	V
R _{PU_BSEL}	BSEL Pin Internal Pull-Up Resistor	(Note 7)	_	50	_	kΩ
I _{DD} (awake)	Supply Current	During 'Awake' Period	_	2.1	_	mA
I _{DD} (sleep)	Supply Current	During 'Sleep' Period	_	2.5	_	μΑ
l= = (aa.)	Average Supply Current	V _{DD} = 1.8V	_	4.3	8	μΑ
I _{DD} (avg)	Average Supply Current	V _{DD} = 3.6V	_	7.2	13	μΑ
tawake	Awake Time	(Note 8)	_	50	100	μs
tperiod	Period	(Note 8)	_	50	100	ms
D.C.	Duty Cycle	_	_	0.1	_	%
tband .	Band Transition Time	(Note 9)	_	100.0	200.1	ms

Notes:

- 7. BSEL pin internal pull-up resistor is only active during AWAKE time.
- When power is initially turned on, the operating V_{DD} (1.6V to 3.6V) must be applied to guarantee the output sampling.
 The output state is valid after the second operating phase (typical 100ms).
- 9. Transition time varies dependent on the timing of BSEL activation during the sleep and awake phases.





Magnetic Characteristics (Note 10 & 11) (T_A = +25°C, V_{DD} = 1.6V to 3.6V, unless otherwise specified.)

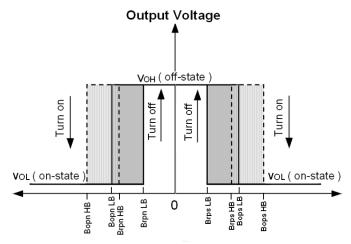
(1mT = 10 Gauss)

BSEL	Symbol	Characteristics	Min	Тур	Max	Unit
Low	Bops _{LB} (South Pole to Part Marking Side)	Low Bond Operation Boint	18	35	55	
Low	Bopn _{LB} (North Pole to Part Marking Side)	Low Band - Operation Point	-55	-35	-18	
Low	Brps _{LB} (South Pole to Part Marking Side)	Low Band - Release Point	12	25	45	
Low	Brpn _{LB} (North Pole to Part Marking Side)	Low Band - Release Point	-45	-25	-12	
High	Bopsнв (South Pole to Part Marking Side)	Lligh Rand Operation Point	43	60	80	Gauss
High	Bopn _{HB} (North Pole to Part Marking Side)	High Band - Operation Point	-80	-60	-43	
High	Brpshb (South Pole to Part Marking Side)	Lligh Bond Bologge Boint	35	50	70	
High	Brpn _{HB} (North Pole to Part Marking Side)	High Band - Release Point	-70	-50	-35	
_	Bhy (Bopx - Brpx)	Hysteresis	_	10	_	

Notes:

- 10. Typical data is at $T_A = +25$ °C, $V_{DD} = 1.8$ V.
- 11. Magnetic characteristics may vary with operating temperature and after soldering.

The AH1898 includes a band select pin (BSEL) so that the operate (Bops and Bopn) and release (Brps and Brpn) points can be adjusted between two pre-defined ranges. The BSEL can be hard wired within the application circuit or the band can be selected on the fly by using the BSEL pin as a logic input. This feature allows the AH1898 sensitivity to be changed by firmware within the application without the addition of any external components. If the BSEL pin is left open circuit the AH1898 defaults to high band.



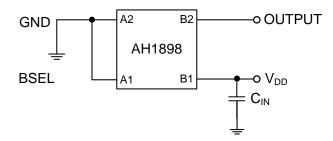
Magnetic flux density B



Application Note

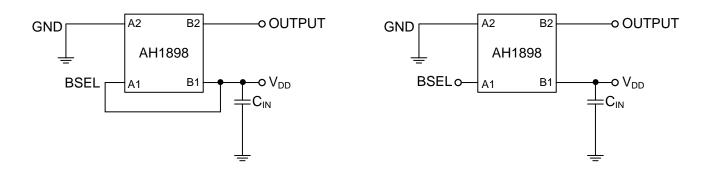
Applications Circuit One - Low Band

Connecting the BSEL pin to ground permanently configures the AH1898 into its high sensitivity mode, requiring a reduced magnetic flux density to activate its output (Low Band).



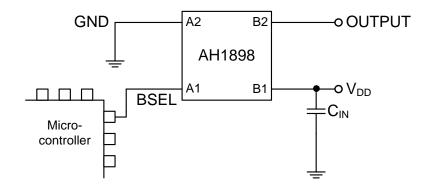
Applications Circuit Two - High Band

Connecting the BSEL pin to V_{DD} or to a voltage greater than 1.4V or leaving the BSEL pin unconnected configures the AH1898 into its low sensitivity mode, requiring a higher magnetic flux density to activate its output (High Band).



Applications Circuit Three - Adjustable Sensitivity

To enhance flexibility within the application, the sensitivity can be adjusted with a standard logic signal allowing it to be controlled by a micro-controller or a logic source. This allows the sensitivity to be changed within the application without a hardware change. Whenever the sensitivity band selection is changed, the band selection changeover should be allowed to complete for the output to be valid.

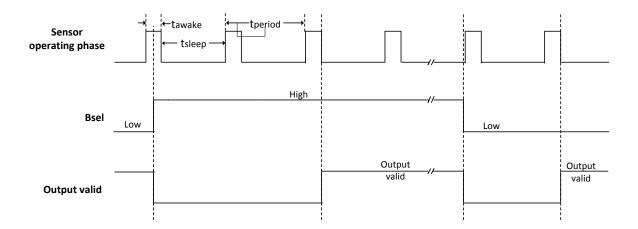




Application Note (continued)

Bands Select Change Timing and Valid Output

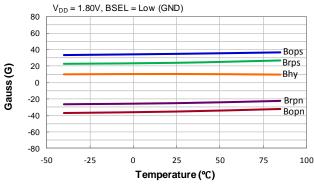
Whenever band selection BSEL pin input is changed, allow for band selection changeover to complete and stabilize. The output is valid only after the second complete operating 'awake' phase. Time taken for the output to be valid, after the BSEL change, depends on timing of BSEL change during the sleep and awake phase; this transition time (t_{BAND}) can range from 100ms typical and 200.1ms maximum.

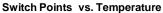


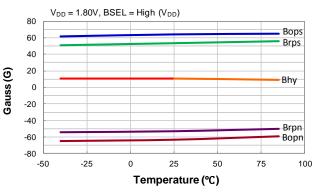


Typical Operating Characteristics

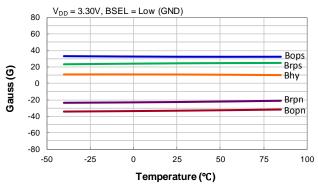
Typical switch points characteristics in low band (BSEL = Low) and high band (BSEL = High)



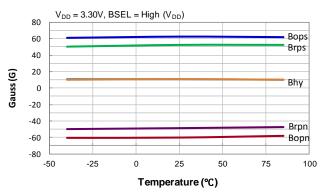




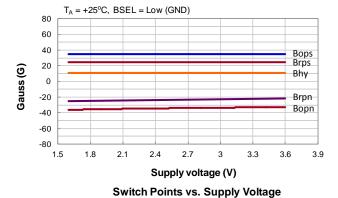
Switch Points vs. Temperature

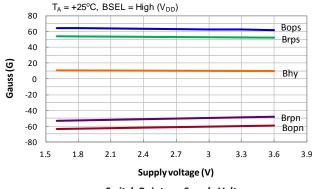


Switch Points vs. Temperature



Switch Points vs. Temperature



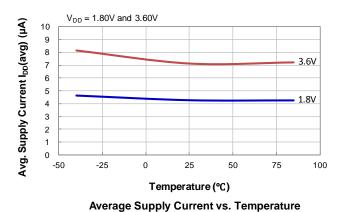


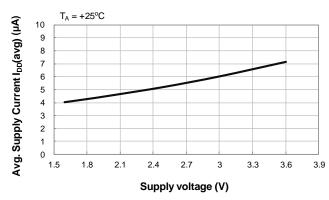
Switch Points vs. Supply Voltage



Typical Operating Characteristics (continued)

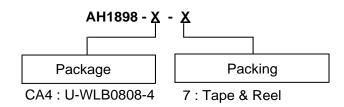
Average Supply Current IDD(avg)





Average Supply Current vs. Supply Voltage

Ordering Information



Part Number	Package	Packaging	7" Tape and Reel		
Part Number	Code	Packaging	Quantity	Part Number Suffix	
AH1898-CA4-7	CA4	U-WLB0808-4	3,000/Tape & Reel	-7	

Marking Information

(1) Package Type: U-WLB0808-4

(Top View)

A2 0 XXB2 В1

 $\frac{XX}{Y}: Identification Code \\ \underline{Y}: Year: 0 to 9$

W: Week: A to Z: 1 to 26 Week;

a to z: 27 to 52 Week; z Represents

52 and 53 Week X: Internal Code

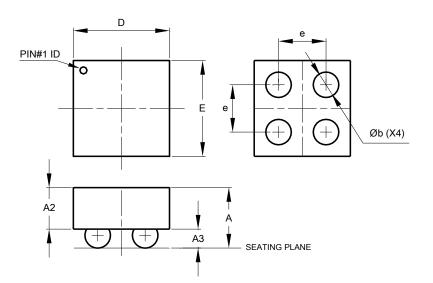
Part Number	Package	Identification Code
AH1898-CA4-7	U-WLB0808-4	B8



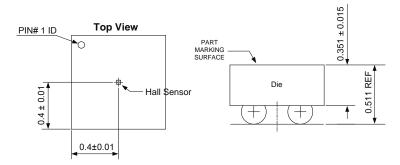
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: U-WLB0808-4



U-WLB0808-4					
Dim	Min Max T		Тур		
Α	0.	511 RE	F		
A2	0.336	0.366	0.351		
A3	0.15	0.17	0.16		
b	0.205	0.225	0.215		
D	0.795	0.825	0.81		
Е	E 0.795 0.825 0.81				
е	-	-	0.40		
All Dimensions in mm					

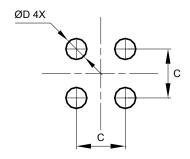


Sensor Location

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: U-WLB0808-4

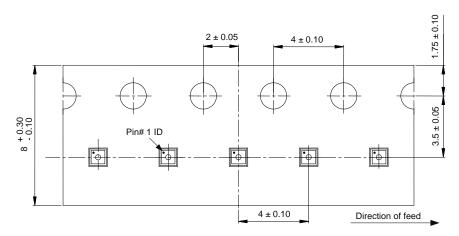


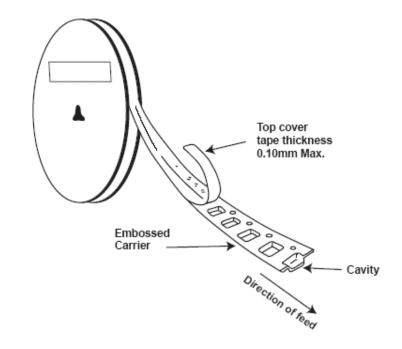
U-WLB0808-4			
Dimensions Value			
C 0.40			
D 0.172			
All Dimensions in mm			



Taping Orientation

Package Type: U-WLB0808-4





Mechanical Data

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Symbol Used to Identify a Tin/Silver/Copper (SnAgCu) Terminal Finish/Ball with A Silver Content >1.5% and No Other Intentionally Added Elements (e1)
- Weight: 0.001 grams (Approximate)



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